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Selection Guide

Description	-10 (Industrial)	Unit
Maximum Access Time	10	ns
Maximum Operating Current	60	mA
Maximum Standby Current	3	mA

Pin Configurations

Figure 1. 48-ball VFBGA pinout (Top View) [1]

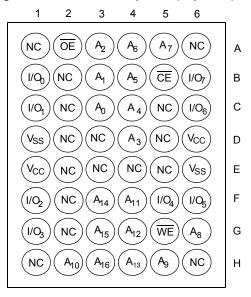
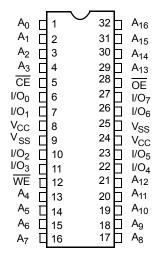


Figure 2. 32-pin SOJ / TSOP II pinout (Top View)



Note

1. NC pins are not connected on the die.



Maximum Ratings

DC Input Voltage [2]	0.3 V to V _{CC} + 0.3 V
Current into Outputs (LOW)	20 mA
Static Discharge Voltage (per MIL-STD-883, Method 3015)	> 2001 V
Latch-up Current	> 200 mA

Operating Range

Range	Ambient Temperature	V _{cc}	Speed
Industrial	–40 °C to +85 °C	$3.3~V\pm0.3~V$	10 ns

Electrical Characteristics

Over the Operating Range

Davamatav	Decemention	Took Conditions		-10 (Inc	lustrial)	Unit
Parameter	Description	Test Conditions		Min	Max	Unit
V _{OH}	Output HIGH voltage	Min V_{CC} , $I_{OH} = -4.0 \text{ mA}$		2.4	_	V
V _{OL}	Output LOW voltage	Min V _{CC} , I _{OL} = 8.0 mA		_	0.4	V
V _{IH}	Input HIGH voltage			2.0	V _{CC} + 0.3	V
V _{IL}	Input LOW voltage [2]			-0.3	0.8	V
I _{IX}	Input leakage current	$GND \le V_{IN} \le V_{CC}$		– 1	+1	μΑ
I _{OZ}	Output leakage current	$GND \le V_{IN} \le V_{CC}$, output disabled		– 1	+1	μΑ
I _{CC}	V _{CC} operating supply current	V _{CC} = Max, I _{OUT} = 0 mA,	100 MHz	_	60	mA
		$f = f_{MAX} = 1/t_{RC}$	83 MHz	_	55	mA
			66 MHz	_	45	mA
			40 MHz	_	30	mA
I _{SB1}	Automatic CE power-down current – TTL inputs	$\begin{aligned} &\text{Max V}_{CC}, \overline{CE} \geq \text{V}_{IH}, \\ &\text{V}_{IN} \geq \text{V}_{IH} \text{ or V}_{IN} \leq \text{V}_{IL}, f = \text{f}_{MAX} \end{aligned}$		_	10	mA
I _{SB2}	Automatic CE power-down current – CMOS inputs	$\begin{aligned} &\text{Max V}_{\text{CC}}, \overline{\text{CE}} \geq \text{V}_{\text{CC}} - 0.3 \text{ V}, \\ &\text{V}_{\text{IN}} \geq \text{V}_{\text{CC}} - 0.3 \text{ V or V}_{\text{IN}} \leq 0.3 \text{ V}, \text{f} = \end{aligned}$	0	ı	3	mA

Note

2. $V_{IL(min)}$ = -2.0 V and $V_{IH(max)}$ = V_{CC} + 1 V for pulse durations of less than 5 ns.

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Capacitance

Parameter [3]	Description	Test Conditions	Max	Unit
C _{IN}	Input Capacitance	$T_A = 25 ^{\circ}\text{C}, f = 1 \text{MHz}, V_{CC} = 3.3 \text{V}$	8	pF
C _{OUT}	Output Capacitance		8	pF

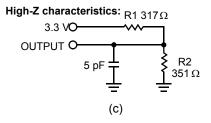
Thermal Resistance

Parameter	Description	Test Conditions	32-pin SOJ	32-pin TSOP II	48-ball VFBGA	Unit
Θ_{JA}		Still Air, soldered on a 3 × 4.5 inch, four-layer printed circuit		62.22	36	°C/W
$\Theta_{\sf JC}$	Thermal Resistance (Junction to Case)	board	38.14	21.43	9	°C/W

AC Test Loads and Waveforms

Figure 3. AC Test Loads and Waveforms [4]





Notes

- 3. Tested initially and after any design or process changes that may affect these parameters.
- 4. AC characteristics (except High Z) are tested using the load conditions shown in Figure 3 (a). High Z characteristics are tested for all speeds using the test load shown in Figure 3 (c).



Data Retention Characteristics

Over the Operating Range

Parameter	Description	Conditions	Min	Max	Unit
V_{DR}	V _{CC} for data retention		2.0	-	V
I _{CCDR}	Data retention current	$V_{CC} = V_{DR} = 2.0 \text{ V}, \overline{CE} \ge V_{CC} - 0.3 \text{ V},$ $V_{IN} \ge V_{CC} - 0.3 \text{ V} \text{ or } V_{IN} \le 0.3 \text{ V}$	_	3	mA
t _{CDR} ^[5]	Chip deselect to data retention time		0	_	ns
t _R ^[6]	Operation recovery time		t _{RC}	_	ns

Data Retention Waveform

Figure 4. Data Retention Waveform



- 5. Tested initially and after any design or process changes that may affect these parameters.
 6. Full device operation requires linear V_{CC} ramp from V_{DR} to V_{CC(min.)} ≥ 50 μs or stable at V_{CC(min.)} ≥ 50 μs.



Switching Characteristics

Over the Operating Range

Parameter [7]	Deparintion	-10 (Industrial)		11!4
Parameter 111	Description	Min	Max	Unit
Read Cycle		•		_
t _{power} ^[8]	V _{CC} (typical) to the first access	100	_	μS
t _{RC}	Read cycle time	10	_	ns
t _{AA}	Address to data valid	_	10	ns
t _{OHA}	Data hold from address change	3	_	ns
t _{ACE}	CE LOW to data valid	_	10	ns
t _{DOE}	OE LOW to data valid	_	5	ns
t _{LZOE}	OE LOW to low Z [9]	0	_	ns
t _{HZOE}	OE HIGH to high Z [9, 10]	_	5	ns
t _{LZCE}	CE LOW to low Z [9]	3	_	ns
t _{HZCE}	CE HIGH to high Z [9, 10]	_	5	ns
t _{PU} ^[11]	CE LOW to power-up	0	_	ns
t _{PD} ^[11]	CE HIGH to power-down	_	10	ns
Write Cycle [12	, 13]			
t _{WC}	Write cycle time	10	-	ns
t _{SCE}	CE LOW to write end	8	_	ns
t _{AW}	Address set-up to write end	8	_	ns
t _{HA}	Address hold from write end	0	_	ns
t _{SA}	Address set-up to write start	0	_	ns
t _{PWE}	WE pulse width	7	_	ns
t _{SD}	Data set-up to write end		_	ns
t _{HD}	Data hold from write end	0	_	ns
t _{LZWE}	WE HIGH to low Z [9]	3	_	ns
t _{HZWE}	WE LOW to high Z [9, 10]	_	5	ns

- 7. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V.

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- 12. The internal write time of the memory is defined by the overlap of CE LOW and WE LOW. CE and WE must be LOW to initiate a write, and the transition of any of these signals can terminate the write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the write.

 13. The minimum write cycle time for Write Cycle no. 3 (WE controlled, OE LOW) is the sum of t_{HZWE} and t_{SD}.



Switching Waveforms

Figure 5. Read Cycle No. 1 (Address Transition Controlled) [14, 15]

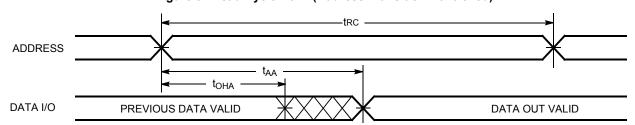
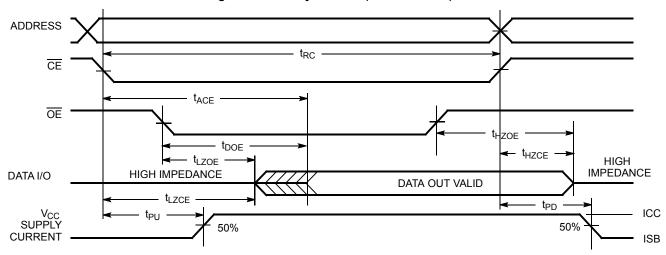


Figure 6. Read Cycle No. 2 ($\overline{\rm OE}$ Controlled) $^{[15,\ 16]}$



Notes

14. <u>Dev</u>ice is continuously selected. OE, CE = V_{IL}.

15. WE is HIGH for Read cycle.

16. Address valid prior to or coincident with CE transition LOW.



Switching Waveforms (continued)

Figure 7. Write Cycle No. 1 (CE Controlled) [17, 18]

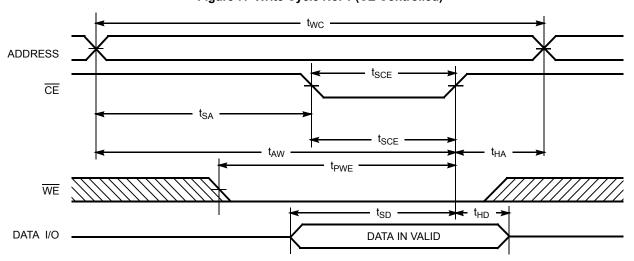
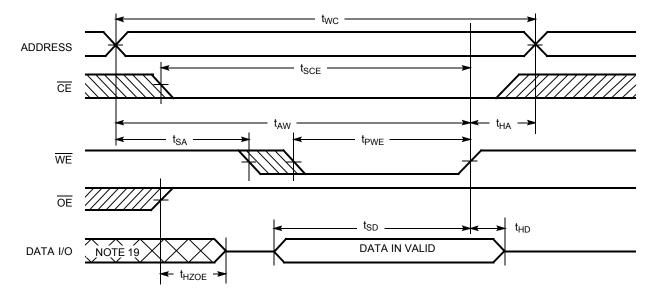


Figure 8. Write Cycle No. 2 (WE Controlled, OE HIGH During Write) [17, 18]



Notes

19. During this period the I/Os are in the output state and input signals should not be applied.

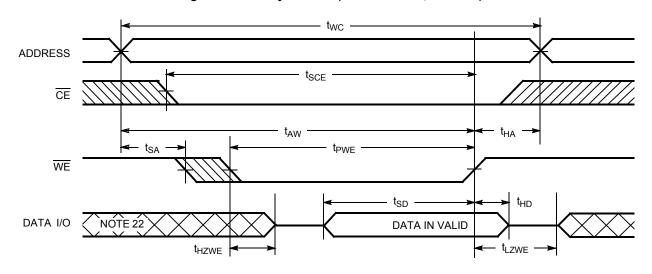
^{17.} Data I/O is high impedance if $\overline{\text{OE}} = V_{\text{Id}}$.

18. If $\overline{\text{CE}}$ goes HIGH simultaneously with WE going HIGH, the output remains in a high-impedance state.



Switching Waveforms (continued)

Figure 9. Write Cycle No. 3 (WE Controlled, OE LOW) [20, 21]



^{20.} If CE goes HIGH simultaneously with WE going HIGH, the <u>output</u> remains in a high-impedance state.

21. The minimum write cycle time for Write Cycle no. 3 (WE controlled, OE LOW) is the sum of t_{HZWE} and t_{SD}.

22. During this period the I/Os are in the output state and input signals should not be applied.



Truth Table

CE	OE	WE	I/O ₀ –I/O ₇	Mode	Power
Н	Х	Х	High Z	Power-Down	Standby (I _{SB})
L	L	Н	Data Out	Read	Active (I _{CC})
L	Х	L	Data In	Write	Active (I _{CC})
L	Н	Н	High Z	Selected, Outputs Disabled	Active (I _{CC})

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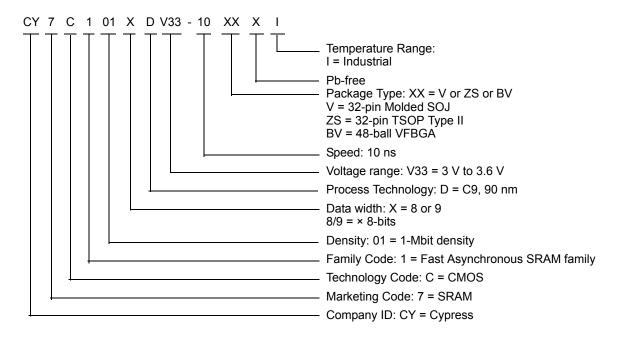


Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
10	CY7C1018DV33-10VXI	51-85041	32-pin (300-Mil) Molded SOJ (Pb-free)	Industrial
	CY7C1019DV33-10VXI	51-85033	32-pin (400-Mil) Molded SOJ (Pb-free)	
	CY7C1019DV33-10ZSXI	51-85095	32-pin TSOP Type II (Pb-free)	
	CY7C1019DV33-10BVXI	51-85150	48-ball VFBGA (Pb-free)	

Please contact your local Cypress sales representative for availability of these parts.

Ordering Code Definitions

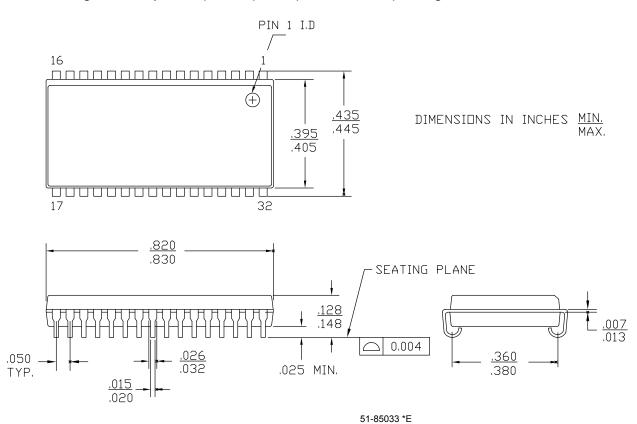


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Package Diagrams

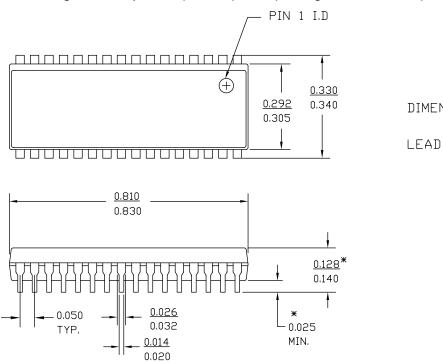
Figure 10. 32-pin SOJ (400 Mils) V32.4 (Molded SOJ V33) Package Outline, 51-85033





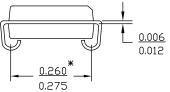
Package Diagrams (continued)

Figure 11. 32-pin SOJ (300 Mils) V32.3 (Catalog 32.3 Molded SOJ) Package Outline, 51-85041



51-85041 Rev. *C

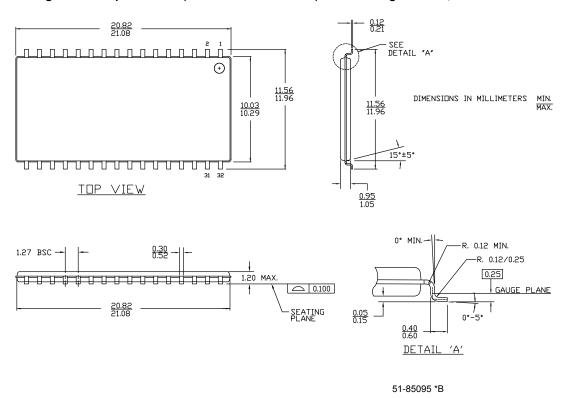
DIMENSIONS IN INCHES $\frac{\text{MIN.}}{\text{MAX.}}$ LEAD COPLANARITY 0.004 MAX.





Package Diagrams (continued)

Figure 12. 32-pin TSOP II (20.95 × 11.76 × 1.0 mm) ZS32 Package Outline, 51-85095

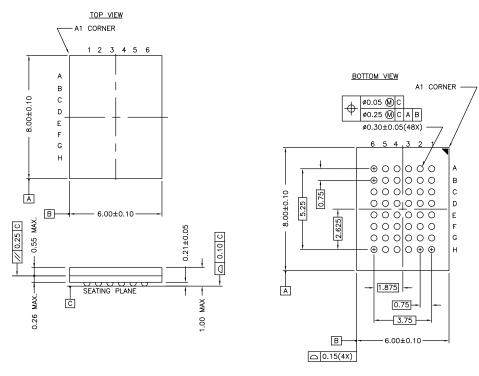


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Package Diagrams (continued)

Figure 13. 48-ball VFBGA (6 × 8 × 1.0 mm) BV48/BZ48 Package Outline, 51-85150



NOTE:
PACKAGE WEIGHT: See Cypress Package Material Declaration Datasheet (PMDD) posted on the Cypress web.

51-85150 *H



Acronyms

Acronym	Description			
CE	Chip Enable			
CMOS	Complementary Metal Oxide Semiconductor			
I/O	Input/Output			
OE	Output Enable			
SOJ	Small Outline J-lead			
SRAM	Static Random Access Memory			
TSOP	Thin Small Outline Package			
TTL	Transistor-Transistor Logic			
VFBGA	Very Fine-Pitch Ball Grid Array			
WE	Write Enable			

Document Conventions

Units of Measure

Symbol	Unit of Measure			
°C	degree Celsius			
MHz	megahertz			
μΑ	microampere			
μS	microsecond			
mA	milliampere			
mm	millimeter			
ns	nanosecond			
Ω	ohm			
%	percent			
pF	picofarad			
V	volt			
W	watt			

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Document History Page

	ocument Title: CY7C1018DV33/CY7C1019DV33, 1-Mbit (128 K × 8) Static RAM ocument Number: 38-05481						
Rev.	ECN No.	Issue Date	Orig. of Change	Description of Change			
**	201560	See ECN	SWI	Advance Information data sheet for C9 IPP			
*A	233750	See ECN	RKF	DC parameters modified as per EROS (Spec # 01-02165 Rev *A) Pb-free Offering in Ordering Information			
*B	262950	See ECN	RKF	Added Data Retention Characteristics table Added T _{power} Spec in Switching Characteristics table Shaded Ordering Information			
*C	307598	See ECN	RKF	Reduced Speed bins to -8 and -10 ns			
*D	520652	See ECN	VKN	Changed status from Preliminary to Final Removed Commercial Operating range Removed 8 ns speed bin Added I _{CC} values for the frequencies 83 MHz, 66 MHz and 40 MHz Added 48-ball VFBGA package Updated Thermal Resistance table Updated Ordering Information table Changed Overshoot spec from V _{CC} + 2 V to V _{CC} + 1 V in footnote #3			
*E	3110052	12/14/2010	AJU	Added Ordering Code Definitions. Updated Package Diagrams.			
*F	3416342	10/20/2011	TAVA	Updated Functional Description (Removed the Note "For guidelines on SRAN system design, please refer to the 'System Design Guidelines' Cypress application note, available on the internet at www.cypress.com." and its reference in Functional Description). Updated Electrical Characteristics. Updated Switching Waveforms. Updated Package Diagrams. Added Acronyms and Units of Measure. Updated in new template.			
*G	4324792	03/28/2014	VINI	Added CY7C1018DV33 related information across the document. Updated Ordering Information (Updated part numbers). Updated Package Diagrams: spec 51-85033 – Changed revision from *D to *E. spec 51-85150 – Changed revision from *G to *H. Updated in new template.			
*H	4531367	10/10/2014	NILE	Corrected the package diagram reference for CY7C1018DV33 in Ordering Information (Updated part numbers). Added 51-85041: 32-pin (300 Mil) Molded SOJ in Package Diagrams:			

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